

(4)

Unit-I / FkæF-I

7½

A

(Printed Pages 7)

2. A circuit containing an inductance and a capacitance in parallel has an alternating current flowing through it. Obtain the resonant frequency. Point out the difference between series and parallel resonant circuits.

Skeâ Øj keálJe meeeveevlej cellSkeâ mellef \$e mespe[ e nwleLee Gmecl  
ØlÙeljelee0ej e Øleee[n le nesj ner nw hef heLe keâr Devergeeoer Deeljeobe  
%eel e keæepes~ BeCeer SJebmeeevevlej Devergeeoer hef heLel[cellDevlej  
keâe GuueKe keæepes~

3. Describe the method for finding the value of high resistance of the order of mega ohms by the method of leakage. Can this method be used for measuring low resistance? Explain it.

cejeee Deense ceeve keâ GÛÛe Øeljej eØe keæes %eel e keajves keâ elueS  
ueekape eldeDe keâe JeCelle keæepes~ Fme eldeDe Eeje keâe eluecve  
Øeljej eØe keâe ceeve %eel e keâe ppe mekeâlee nW Fmes mecePeeFÙes

Roll No. \_\_\_\_\_

**S-602**

B.Sc. (Part-I) Examination, 2015

(Regular & Exempted)

**PHYSICS**

Second Paper

(Circuit Fundamental & Basic Electronics)

**Time Allowed : Three Hours ] [ Maximum Marks : 50**

Note : Question No.1 is compulsory and attempt one question from each Units I, II, III and IV. Thus answer five questions in all.

ØlÙe meb1 DeefrejeÙe&nwleLee ØlÙekâ FkæF-I, II, III SJel  
IV mes Skeâ ØlÙe keæepes~ Fme Økeâej kegue heâle ØlÙeekâ  
Gøej oepes~

1. Write short answers of the following:  $2 \times 10 = 20$   
eluecvekele keâe mellehle Gøej oepes :  
(i) Show that in a resonant LCR Circuit sharpness of resonance is equal to the quality factor of the resonant circuit.

(2)

oMeeFÜes ekaā BeSeer Devegeeo LCR hefj heLe celWDevegeeo keā  
leaffCelee keāeefuešer iefj keā yej eyej neefer nW

- (ii) How is an A.C. bridge different from a D.C. bridge?

BeLÜejelcea Oeej e mefey Skeā ebš Oeej e mefegmes  
ekēaj  
efeve neefer nP

- (iii) How are the thickness and degree of doping different in the emitter, base and collector of a transistor?

ekāmer Šepemšj keā Glmepelka, DeOej SJeb mebeenkeā keā  
OeeF& SJeb [eshelle keā ceesee celWkeēle efvelvee neefer nP

- (iv) Explain the difference between voltage negative feedback and current negative feedback.

Jesūšlē \$e+Ceelcekeā heyej Ce SJebOej \$e+Ceelcekeā heyej Ce  
celWDevlej mecePeeFÜes

- (v) Differentiate between conductor, semiconductor and insulator.

Oeeukeā, DeOelueukeā Je kefjOeeukeā celWDevlej yeleFS~

(3)

- (vi) If the value of  $\alpha_{dc}$  of a transistor is 0.98, what is the value of  $\beta_{dc}$  for the same transistor?

Uebf ekaāmer Šepemšj keā eueS  $\alpha_{dc}$  keā ceeve 0.98 ny lef  
Gmeer Šepemšj keā eueS  $\beta_{dc}$  keā ceeve keflee neefer?

- (vii) What is the difference between Zener and Avalanche breakdown?

perej leLē DejeOejle effepeve celWkeēle Delej nP

- (viii) Why is modulation necessary for radio communication?

jefjUes meflej Ce keā eueS ceefjemeve kefleeWDejeMüekeā nP

- (ix) What is the function of a filter circuit?

efeaūšj hefj heLe keā keflee keāeule&neflee nP

- (x) Explain the terms frequency response and bandwidth.

DejeOejle Devegeelce Sjb hefjkeā- OeeF& keā keflee DeLe&nP  
mecePeeFS~

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Unit-II / FkæF-11

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4. Explain how potential barrier arises in a P-N junction diode? Describe the working of a P-N junction diode under forward and reverse biasing. How is the resistance of the diode affected under both these conditions?

P-N meðføe [elðes] celvjeðekā elleYele keimes Gheve n ee nP  
mecePeeFÙes P-N meðføe [elðes] keærkeæðe&leDe keæðe Deevæveelle  
IeLee heSe Deevæveelle keæðe Devleieðe JeCøte keæðe eS~ Fve oeyed  
hefj ðmLællæðellæW [elðes] keæðe leYele hej keæðe leYele hej Lee nP

5. Draw the circuit diagram of a half-wave rectifier with a suitable filter and a zener diode as voltage regulator. Calculate the rectification efficiency of a half-wave rectifier. What do you mean by voltage regulation?

hefj heLe elðe Þeje Skeð Deæðej he eb-skæðejer keæðe oMeafÙes epemekæ  
meelæ Skeð Gheljøjaðaðaušj IeLee Skeð pøej [elðes] elleYele elðeðekæ  
keæ ðmhe celvæiee nes Deæðej he eb° keæðejer keæðe eb° keæðejer #ecele  
%ele keæðeS~ elleYele elðeðekæ mes Deæðe keæðe mecePøes nP

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Unit-I/III / Unit-I/III

7½

6. Draw the circuit diagram of a p-n-p transistor in common emitter configuration. Discuss the characteristic Curves. Establish the relation:

$$I_c = \beta_{dc} I_B + I_{CEO}$$

Where the symbols have their usual meaning

What is  $I_{CEO}$  ?

Gjeljecece Gjeljecece cel p-n-p Štopenšj keke hef hele  
eljece yeveeFües Deeljecece keke Jeeljecece eljece kekepeS~  
efecveeKele mecyevOe keke mLeehele kekepeS :

$$I_c = \beta_{dc} I_B + I_{CEO}$$

peneBhej řelekeak mJele: mhe° nP

$$I_{CEO} \text{ keke nP}$$

7. Describe the action of an emitter follower by drawing a neat diagram. Derive the expression for voltage gain, input impedance and output impedance of the emitter follower.

mJeljecece Kekeljecece Gjeljecece keke Jeeljecece mecyevOeFües

(7)

Fmekak Jeesišlee ueeYe, eljelemer řelleyeOe Šjeljeviče řelleyeOe keke  
Jüeljekeak Jüeljeheve kekepeS~

Unit-I/IV / Unit-I/IV

7½

8. What is an oscillator? Derive Barkhausen Criterion for oscillation. With the help of a circuit diagram discuss the working of an oscillator using a transistor.

oeljekeak keke nP oeljeve keke eljeS yekeljeGmeke keke xakefulekak  
řelleyeDe Jüeljeheve kekepeS~ hef hele eljece kekeceo mes ekameer Sme  
oeljekeak keke řekeljeleDe keke eljelevee kekepeS epemekell Štopenšj  
řeljegea ekeake ielje nes

9. Write notes on any two of the following:

efecveeKele cellmes ekavneRoes hej ešhheeCejeB eueKeS:

(a) Amplitude modulation

Deeljecece cee[geve

(b) Deflection sensitivity of CRO

CRO keke eljeheve megeefulee

(c) Effects of negative feedback in amplifiers

\$eCeelcekeak hegeve Ce keke řejeleka hej DeVeeje